

Design Example Report

Title	15W power supply using TNY268P
Specification	Input: 120 - 420 Vdc Output: 5V/3A, 13V/10mA
Application	PC Standby
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Summary and Features

This report details the design of an isolated Flyback converter for a PC Standby power supply.

- High light load efficiency
- Over 0.4W out at 1W in, as measured in the PC PSU
- Total output power 15 W with TNY268P and EE19 core
- Typical Efficiency 79 %
- Meets \pm 5 % output voltage regulation over line and load changes

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Important Notes:

Although the prototype hardware is designed to satisfy safety isolation requirements, this engineering prototype has not been agency approved. Therefore all testing should be performed using an isolation transformer to provide the AC input to the prototype board.

The layout shown in this report has been engineered to follow Power Integrations' design guidelines to minimize EMI and susceptibility. Changing the layout may worsen EMI and other aspects of performance.

Design Reports contain a power supply design specification, schematic, bill of materials, and transformer documentation. Performance data and typical operation characteristics are included. Typically only a single prototype has been built.



1 Introduction

This document is an engineering report showing the performance characteristics of a 15W Flyback converter with 120–420Vdc (PFC application) input, 5V 3A isolated output, and 13V 10mA non-isolated output. This design uses *TinySwitch-II* – an integrated IC comprising a high voltage *MOSFET*, and *PWM* controller.

This document contains power supply specification, schematic, bill of materials, transformer documentation, printed circuit layout, and performance data. The photos of power supply prototype are shown in Figure 1 and Figure 2.

Measurements were taken both with the prototype standalone, and in the PC power supply.



Figure 1 – Power Supply Prototype – Top View



Figure 2 – Power Supply Prototype – Bottom View



Note: Y-cap is for testing the unit standalone. Otherwise, The common-mode noise may affect the input power measurements.

2 Power Supply Specification

Description	Symbol	Min	Тур	Max	Units	Comment
Input Voltage	V _{IN}	120		420	Vdc	PFC Standby
Outputs						
Output Voltage 1 Output Ripple Voltage 1 Output Current 1	V _{out1} V _{ripple1} I _{out1}	4.75	5.0	5.25 50 3	V mV A	± 5% 20 MHz Bandwidth isolated
Output Voltage 2 Output Ripple Voltage 2 Output Current 2 Continuous Output Power	V _{out2} V _{ripple2} I _{out2} P _{out}		13 15	130 10	V mV mA W	20 MHz Bandwidth non-isolated
Efficiency	η		79		%	At full load
Ambient Temperature	Т _{АМВ}	0		40	°	Free convection, Sea level

Table 1 – Power Supply Specification



3 Schematic



4 PCB Layout



Figure 4 – PCB Layout

Note:

- 1. The schematic and PCB layout have some components as OPTIONS, which are not used in the prototype.
- 2. The prototype PCB layout may not match the schematic, due to modifications made to meet the specifications.



5 Bill Of Materials

Item	Qty	Reference	Description						
1	1	C1	0.01 μF, 1KV, Ceramic capacitor, Z5U						
2	1	C2	1000 pF, 1KV, Ceramic capacitor, Z5U						
3	1	C3	0.1 μF, 50V, Ceramic capacitor, X7R						
4	1	C4	1500 μ F, 10V, Electrolytic capacitor Low ESR, (Rubycon ZL series or equivalent)						
5	1	C5	1000 μ F, 10V, Electrolytic capacitor Low ESR, (Rubycon ZL series or equivalent)						
6	1	C6	470 μF, 10V, Electrolytic capacitor Low ESR, (Rubycon ZL series or equivalent)						
7	1	C7	470 pF, 50V, Ceramic capacitor, NPO						
8	1	C8	47 μF, 50V, Electrolytic capacitor						
9	1	C9	1000 pF, Y1 safety capacitor						
10	1	D1	1N4007GP, 1000V, 1A, glass passivated diode $t_{rr} = 2 \mu S$ (typical)						
11	1	D3	SB540, 40V 5A Schottky diode						
12	1	D4	BZX79 4.3V, 4.3V, 2%, 0.5 W, Zener diode						
13	1	D5	Zener diode option for over voltage protection						
14	1	D6	BAV20, small signal diode, 200V, 200mA						
15	1	D8	P6KE180A, TVS zener, 5W, 180V, 5%						
16	1	L1	3.3 μ H, 3A, Ferrite drum core inductor, # 22 AWG magnet wire						
17	2	R1, R6	10 Ω, 1/4W, 5%, resistor						
18	1	R2	16 KΩ, 1/4W, 5%, resistor						
19	1	R3	0 Ω, 1/8W, 5%, resistor						
20	1	R4	30 Ω, 1/4W, 5%, resistor						
21	1	R5	360 Ω, 1/8W, resistor						
22	1	T1	Transformer EE19 core						
23	1	U1	TNY268P						
24	1	U2	PC817D, Optocoupler						

Table 2 - Bill of Materials



6 Transformer

6.1 Transformer Winding



Figure 5 – Transformer Winding

Note:

1. W1 and W2 are interleaved primary winding. Both flying leads (FL) should be soldered together and wrap with tape for insulation.

6.2 Electrical Specifications

Electrical Strength	60Hz 1minute, from Pins 1-4 to Pins 7-8	3 kV for 1 minute
Primary Inductance (Pin 1 to Pin 2)	All windings open	1.12 mH – 1.18 mH – 1.24 mH
Resonant Frequency	All windings open	300 kHz min.
Primary Leakage Inductance	L ₁₂ with pins 3-8 shorted	25 μH max.

Table 3 – Transformer Electrical Parameters



6.3 Transformer Construction



Figure 6 – Transformer Construction

6.4 Materials

ltem	Description
[1]	Core: EE19, Gapped for AL = 114 nH/T ² - 120 nH/T ² - 127 nH/T ²
[2]	Bobbin: Horizontal 8 pins
[3]	Magnet Wire: # 31 AWG
[4]	Magnet Wire: # 35 AWG
[5]	Triple Insulated Wire # 27 AWG
[6]	Tape: 3M 1298 Polyester Film (white) 0.338" x 2 mils
[7]	Tape: 3M 1298 Polyester Film (white) 0.135" x 2 mils (to wrap the core together)
[8]	Varnish

Table 4 – Transformer BOM



6.5 Winding Instructions

All windings should be wound in the forward direction.

Bobbin orientation	Place the bobbin on the winding machine with pins 1-4 on the right side and pins 5-8 on the left side.
W1 (Primary winding-1)	Wind 66 turns in 2 layers with # 31 AWG magnet wire – first layer 33T from right to left starting from pin 2 – 3 layers of insulation tape – second layer 33T from left to right and finish as flying lead.
Basic Insulation	3 layers of tape for insulation.
W2 (Bias winding)	Wind 12 turns in one layer from left to right with # 35 AWG magnet wire starting temporarily from pin 6 and finish at pin 4, wind evenly across the width of the bobbin – one layer of tape – bring the starting end from pin 6 to pin 3.
Basic Insulation	2 layers of tape for insulation.
W3 (5V Winding)	Wind 5 turns in one layer from left to right with $\#$ 27 x 3 (trifilar) triple insulated wire, starting from pin 8 – one layer of tape – and finish at pin 7.
Basic Insulation	2 layers of tape for insulation.
W4 (Primary winding-2)	Wind 33 turns in one layer with # 31 AWG magnet wire from left to right starting temporarily from pin 8 and finishing at pin 1 – one layer of tape – bring the starting end from pin 8 and terminate as flying lead. Twist the flying leads (W1 and W4 FLs) together.
Outer Insulation	2 layers of tape for insulation.
Core Assembly	Assemble and secure core halves.
Final Assembly	Impregnate transformer uniformly with varnish.

6.6 Design Notes:

Power Integrations Device	TNY268P
Frequency of Operation	132 KHz
Mode	Continuous/ discontinuous
Peak Current	0.55 A
Reflected Voltage (Secondary to Primary)	109 V
Maximum AC Input Voltage	301 Vac
Minimum AC Input Voltage	85 Vac

 Table 5 – Power Supply Design Parameters



7 Transformer Design Spread Sheet

ACDC_TNY- II_Rev1_1_03270 1 Copyright Power Integrations Inc. 2001	INPUT	INFO	OUTPUT	UNIT	ACDC_TNYII_Rev1_1_032701.xls: TinySwitch-II Continuous/Discontinuous Flyback Transformer Design Spreadsheet
ENTER APPLICA	TION				Customer
VACMIN VACMAX fL VO PO n Z	85 301 60 5 15 0.79 0.5			Volts Volts Hertz Volts Watts	Minimum AC Input Voltage Maximum AC Input Voltage AC Mains Frequency Output Voltage Output Voltage Output Power Efficiency Estimate Loss Allocation Factor Bridge Rectifier Conduction Time
tC	3			mSeconds	Estimate
ENTER TinySwitch-II VARIABLES TNY-II Chosen Device ILIMITMIN ILIMITMAX fS fSmin fSmax VOR VDS	TNY268 109 10	TNY268	Power Out 0.512 0.588 132000 120000 144000	Universal 15W Amps Amps Hertz Hertz Hertz Volts Volts	 115 Doubled/230V 23W TINYSwitch Minimum Current Limit TINYSwitch Maximum Current Limit TINYSwitch Switching Frequency TINYSwitch Minimum Switching Frequency (inc. jitter) TINYSwitch Maximum Switching Frequency (inc. jitter) Reflected Output Voltage TINYSwitch on-state Drain to Source Voltage Output Winding Diode Forward Voltage
VD	0.5			Volts	Drop Ripple to Peak Current Ratio
КР			0.74		(0.6 <krp<1.0 1.0<kdp<6.0)<="" :="" th=""></krp<1.0>
Core Type Core	ee19	EE19 FF19_BO		P/N:	PC40EE19-Z
<i>Bobbin</i> AE LE AL BW		BBIN	0.23 3.94 1250 9	<i>P/N:</i> cm^2 cm nH/T^2 mm	BE-19-118CPH Core Effective Cross Sectional Area Core Effective Path Length Ungapped Core Effective Inductance Bobbin Physical Winding Width
Μ	0			mm	Secondary Creepage Distance)



L NS	3 5			Number of Primary Layers Number of Secondary Turns
DC INPUT VOLTAGE PARAMETERS				
VMIN VMAX		116 426	Volts Volts	Minimum DC Input Voltage Maximum DC Input Voltage
DMAX		0.51		Maximum Duty Cycle
IAVG		0.16	Amps	Average Primary Current
IP		0.51	Amps	Minimum Peak Primary Current
IR		0.38	Amps	Primary Ripple Current
IRMS		0.24	Amps	Primary RMS Current
LP		1159	uHenries	Primary Inductance
NP		99		Primary Winding Number of Turns
ALG		118	nH/1^2	Gapped Core Effective Inductance
ВМ		2989	Gauss	Flux Density, IP (BP<3000)
BAC		963	Gauss	(0.5 X Peak to Peak)
ur		1704	Cadoo	Relative Permeability of Ungapped Core
LG		0.22	mm	Gap Length (Lg > 0.1 mm)
BWE		27	mm	Effective Bobbin Width
				Maximum Primary Wire Diameter
OD		0.27	mm	including insulation
INC		0.05		Estimated Total Insulation Thickness (= 2
		0.05	mm	Tilm thickness)
DIA		0.22	mm	Primary Wire Gauge (Rounded to next
AWG		32	AWG	smaller standard AWG value)
				Bare conductor effective area in circular
CM		64	Cmils	mils
СМА		264	Cmils/Amp	Primary Winding Current Capacity (200 < CMA < 500)
Lumped parameters				
ISP		10 15	Amps	Peak Secondary Current
		4 74	Ampo	
		4.74	Amps	Secondary RMS Current
		3.67	Amps	Output Capacitor RMS Ripple Current
		0.07	Апрэ	Secondary Bare Conductor minimum
CMS		948	Cmils	circular mils Secondary Wire Gauge (Rounded up to
AWGS		20	AWG	next larger standard AWG value) Secondary Minimum Bare Conductor
DIAS		0.81	mm	Diameter Secondary Maximum Outside Diameter
ODS		1.80	mm	for Triple Insulated Wire



INSS	0.49	mm	Maximum Secondary Insulation Wall Thickness	
VDRAIN	675	Volts	Maximum Drain Voltage Estimate (Includes Effect of Leakage Inductand	
PIVS	26	Volts	Voltage	

8 Performance Data

The measurements were taken for the power supply in two ways:

- 1) As a stand-alone unit, and
- 2) In a PC power supply, operating in standby mode

A comparison was made against the original standby power supply (*TOP244P* design) in the PC power supply.

The measurements as stand-alone unit are given in the table below. 13V output is not loaded.



8.1 Light Load Input and Output Power Comparison

These measurements were taken of the whole PSU, in standby mode. A comparison is made with the original standby design, against the TinySwitch-II design. For the measurements, the original standby supply was removed and the TinySwitch-II prototype was wired in. In both cases, the standby supply was powering the primary-side 13V circuits in the PSU.



Figure 7 – Input vs. Output power at 115 Vac



Figure 8 – Input vs. Output power at 230 Vac



8.2 Efficiency comparison, standalone

The efficiency of the TNY268P design is % higher than the TOP244P design, especially at light load.



Figure 9 - Efficiency versus output current at 115 Vac



Figure 10 – Efficiency versus output current at 230 Vac



9 Output Ripple Measurements

9.1 Ripple Measurement Technique

For DC output ripple measurements, a modified oscilloscope test probe must be utilized in order to reduce spurious signals due to pickup. Details of the probe modification are provided in Figure 11 and Figure 12.

The 5125BA probe adapter is affixed with two capacitors tied in parallel across the probe tip. The capacitors include one (1) 0.1 μ F/50 V ceramic type and one (1) 1.0 μ F/50 V aluminum electrolytic. The aluminum electrolytic type capacitor is polarized, so proper polarity across DC outputs must be maintained (see below).



Figure 11 – Oscilloscope Probe Prepared for Ripple Measurement. (End Cap and Ground Lead Removed)



Figure 12 - Oscilloscope Probe with Probe Master 5125BA BNC Adapter

(Modified with wires for probe ground for ripple measurement, and two parallel decoupling capacitors added).



9.2 Output Voltage Ripple



Figure 13 – 5V Output Voltage Ripple at V_{IN} = 115 Vac, I_{5V} = 3 A

10 Revision History

Date	Author	Revision	Description & changes	Reviewed
February 4, 2004	MJ	1.0	Initial release	VC/AM



Notes



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